

## REFERENCE FREQUENCY 16.368 MHz, 2nd IF FREQUENCY 4.092 MHz RF/IF FREQUENCY DOWN-CONVERTER + PLL FREQUENCY SYNTHESIZER IC FOR GPS RECEIVER

### DESCRIPTION

The  $\mu$ PB1007K is a silicon monolithic integrated circuit for GPS receiver. This IC is designed as double conversion RF block integrated Pre-Amplifier + RF/IF down-converter + PLL frequency synthesizer on 1 chip.

This IC is lower current than the  $\mu$ PB1005K and packaged in a 36-pin QFN package.

This IC is manufactured using our 30 GHz  $f_{\max}$  UHS0 (Ultra High Speed Process) silicon bipolar process.

### FEATURES

- Double conversion :  $f_{\text{REFin}} = 16.368 \text{ MHz}$ ,  $f_{1\text{stIFin}} = 61.380 \text{ MHz}$ ,  $f_{2\text{ndIFin}} = 4.092 \text{ MHz}$
- Integrated RF block : Pre-Amplifier + RF/IF frequency down-converter + PLL frequency synthesizer
- Needless to input counter data : fixed division internal prescaler
  - VCO side division :  $\div 200$  ( $\div 25$ ,  $\div 8$  serial prescaler)
  - Reference division :  $\div 2$
- Supply voltage :  $V_{\text{CC}} = 2.7 \text{ to } 3.3 \text{ V}$
- Low current consumption :  $I_{\text{CC}} = 25.0 \text{ mA TYP. @ } V_{\text{CC}} = 3.0 \text{ V}$
- Gain adjustable externally : Gain control voltage pin (control voltage up vs. gain down)
- On-chip pre-amplifier :  $G_{\text{P}} = 15.5 \text{ dB TYP. @ } f = 1.57542 \text{ GHz}$   
 $\text{NF} = 3.2 \text{ dB TYP. @ } f = 1.57542 \text{ GHz}$
- Power-save function : Power-save dark current  $I_{\text{CC}}(\text{PD}) = 5 \mu\text{A MAX.}$
- High-density surface mountable : 36-pin plastic QFN

### APPLICATIONS

- Consumer use GPS receiver of reference frequency 16.368 MHz, 2nd IF frequency 4.092 MHz (for general use)

### ORDERING INFORMATION

| Part Number        | Package            | Supplying Form  |
|--------------------|--------------------|---|
| $\mu$ PB1007K-E1-A | 36-pin plastic QFN | <ul style="list-style-type: none"> <li>• 12 mm wide embossed taping</li> <li>• Pin 1 indicates pull-out direction of tape</li> <li>• Qty 2.5 kpcs/reel</li> </ul> |

**Remark** To order evaluation samples, contact your nearby sales office.

Part number for sample order:  $\mu$ PB1007K-A

### Caution Electro-static sensitive devices

The information in this document is subject to change without notice. Before using this document, please confirm that this is the latest version.

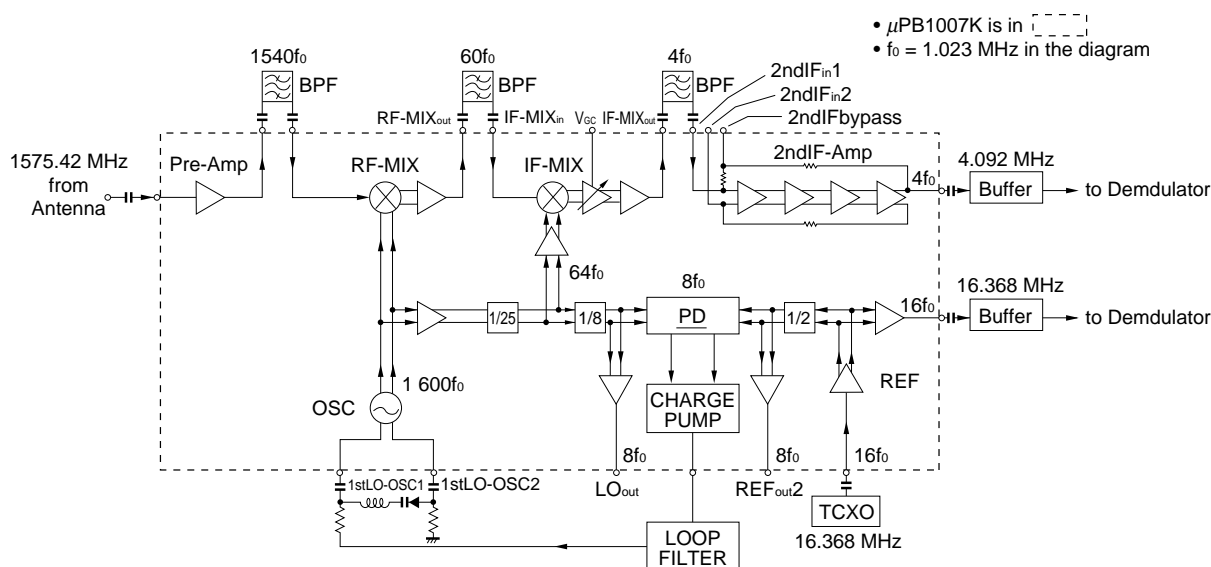
**PRODUCT LINE-UP** ( $T_A = +25^\circ\text{C}$ ,  $V_{CC} = 3.0\text{ V}$ )

| Type  | Part Number    | Functions<br>(Frequency unit: MHz)   | $V_{CC}$<br>(V) | $I_{CC}$<br>(mA) | CG<br>(dB)    | Package             | Status     |
|---|----------------|--|-----------------|------------------|---------------|---------------------|------------|
| Clock<br>Frequency<br>Specific<br>1 chip IC | $\mu$ PB1007K  | Pre-amplifier + RF/IF<br>down-converter + PLL<br>synthesizer<br>REF = 16.368<br>1stIF = 61.380/2ndIF = 4.092 | 2.7 to 3.3      | 25.0             | 100 to<br>120 | 36-pin plastic QFN  | New Device |
|   | $\mu$ PB1005GS | RF/IF down-converter<br>+ PLL synthesizer  | 2.7 to 3.3      | 45.0             | 76 to 96      | 30-pin plastic SSOP | Available  |
|   | $\mu$ PB1005K  | REF = 16.368<br>1stIF = 61.380/2ndIF = 4.092   |                 |                  |               | 36-pin plastic QFN  |            |

**Remark** Typical performance. Please refer to ELECTRICAL CHARACTERISTICS in detail.  
To know the associated products, please refer to their latest data sheets.

**SYSTEM APPLICATION EXAMPLE**

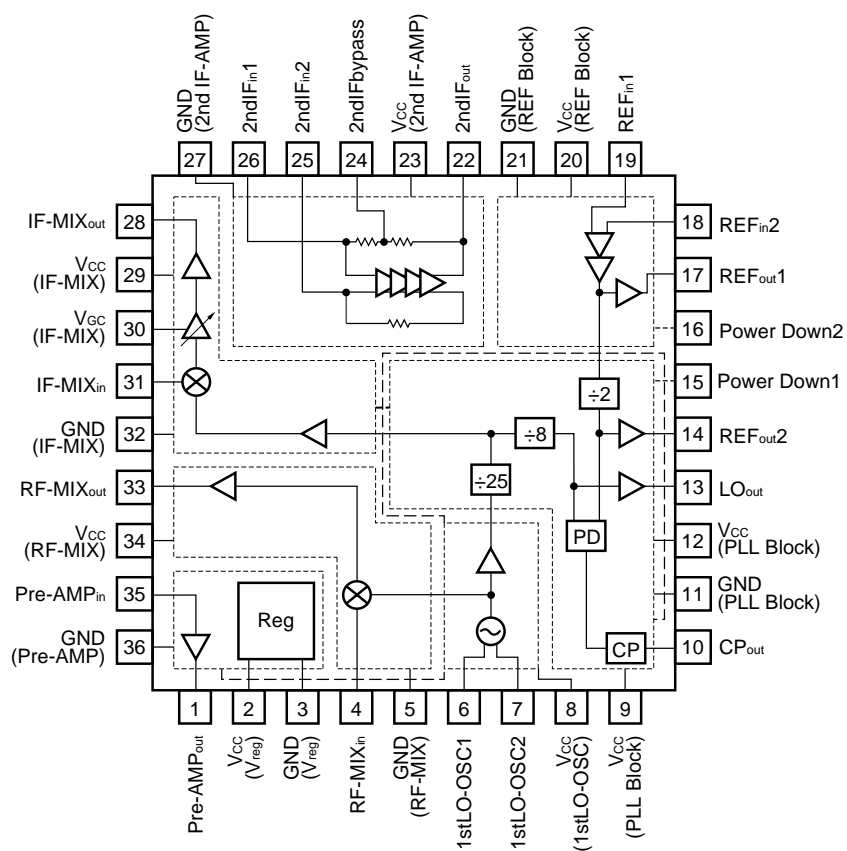
GPS receiver RF block diagram



**Caution** This diagram schematically shows only the  $\mu$ PB1007K's internal functions on the system.  
This diagram does not present the actual application circuits.

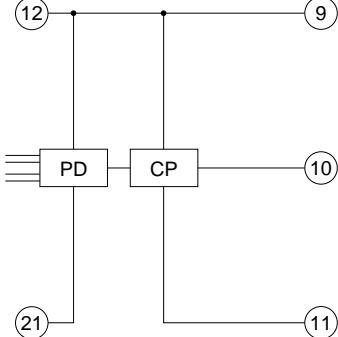
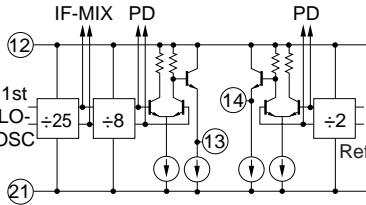
## PIN CONNECTION AND INTERNAL BLOCK DIAGRAM

Top View



## PIN EXPLANATION

| Pin No. | Pin Name                            | Applied Voltage (V) | Pin Voltage (V)                    | Function and Application   | Internal Equivalent Circuit |
|---------|-------------------------------------|---------------------|------------------------------------|--|-----------------------------|
| 1       | Pre-AMP <sub>out</sub>              | –                   | voltage as same as V <sub>CC</sub> | Output pin of Pre-amplifier. Output biasing and matching required as it is a open collector output.  |                             |
| 2       | V <sub>CC</sub> (V <sub>reg</sub> ) | 2.7 to 3.3          | –                                  | Supply voltage pin of voltage regulator. This pin should be externally equipped with bypass capacitor to minimize ground impedance.                                    |                             |
| 3       | GND(V <sub>reg</sub> )              | 0                   | –                                  | Ground pin of voltage regulator.   |                             |
| 35      | Pre-AMP <sub>in</sub>               | –                   | 0.79                               | Input pin of Pre-amplifier. LC matching circuit must be connected to this pin.   |                             |
| 36      | GND(Pre-AMP)                        | 0                   | –                                  | Ground pin of Pre-amplifier.   |                             |
| 4       | RF-MIX <sub>in</sub>                | –                   | 1.00                               | Input pin of RF mixer. 1 575.42 MHz band pass filter can be inserted between pin 1 and 4.  |                             |
| 5       | GND(RF-MIX)                         | 0                   | –                                  | Ground pin of RF mixer.  |                             |
| 33      | RF-MIX <sub>out</sub>               | –                   | 1.30                               | Output pin of RF mixer. 1st IF filter must be inserted between pin 31 and 33.  |                             |
| 34      | V <sub>CC</sub> (RF-MIX)            | 2.7 to 3.3          | –                                  | Supply voltage pin of RF mixer. This pin should be externally equipped with bypass capacitor to minimize ground impedance.   |                             |
| 6       | 1stLO-OSC1                          | –                   | 1.80                               | Pin 6 and 7 are each base pin of differential amplifier for 1st LO oscillator. These pins should be equipped with LC and varactor to oscillate on 1 636.80 MHz as VCO. |                             |
| 7       | 1stLO-OSC2                          | –                   | 1.80                               |  |                             |
| 8       | V <sub>CC</sub> (1stLO-OSC)         | 2.7 to 3.3          | –                                  |  |                             |

| Pin No. | Pin Name                    | Applied Voltage (V)  | Pin Voltage (V)                             | Function and Application   | Internal Equivalent Circuit  |     |      |    |  |
|---------|-----------------------------|----------------------|---|--|--|-----|------|----|--|
| 9       | V <sub>CC</sub> (PLL Block) | 2.7 to 3.3           | –   | Supply voltage pin of PLL block. This pin should be externally equipped with bypass capacitor to minimize ground impedance.  |   |     |      |    |  |
| 10      | CP <sub>out</sub>           | –                    | Output in accordance with phase difference. | Output pin of charge-pump. This pin should be equipped with external RC in order to adjust dumping factor and cut-off frequency. This tuning voltage output must be connected to varactor diode of 1stLO-OSC.  |  |     |      |    |  |
| 11      | GND(PLL Block)              | 0                    | –   | Ground pin of PLL block.   |  |     |      |    |  |
| 12      | V <sub>CC</sub> (PLL Block) | 2.7 to 3.3           | –   | Supply voltage pin of PLL block. This pin should be externally equipped with bypass capacitor to minimize ground impedance.  |  |     |      |    |  |
| 13      | LO <sub>out</sub>           | –                    | 1.85  | Monitor pin of 1/200 prescaler output.   |  |     |      |    |  |
| 14      | REF <sub>out2</sub>         | –                    | 1.68  | Monitor pin of 1/2 prescaler output.   |  |     |      |    |  |
| 15      | Power Down1                 | 0 or V <sub>CC</sub> | –   | Stand-by mode control pin of Pre-amplifier block, 1stLO-OSC block, charge pump prescaler block, LO output amplifier, RF mixer, IF mixer, 2ndIF amplifier. <div><table><tr><td>Low</td><td>OFF</td></tr><tr><td>High</td><td>ON</td></tr></table></div> | Low  | OFF | High | ON |  |
| Low     | OFF                         |                      |   |  |  |     |      |    |  |
| High    | ON                          |                      |   |  |  |     |      |    |  |

| Pin No. | Pin Name                     | Applied Voltage (V)  | Pin Voltage (V) | Function and Application   | Internal Equivalent Circuit |     |      |    |  |
|---------|------------------------------|----------------------|-----------------|--|-----------------------------|-----|------|----|--|
| 16      | Power Down2                  | 0 or V <sub>CC</sub> | –               | Stand-by mode control pin of reference block.<br><table border="1"><tr><td>Low</td><td>OFF</td></tr><tr><td>High</td><td>ON</td></tr></table>                                      | Low                         | OFF | High | ON |  |
| Low     | OFF                          |                      |                 |  |                             |     |      |    |  |
| High    | ON                           |                      |                 |  |                             |     |      |    |  |
| 17      | REF <sub>out</sub> 1         | –                    | –               | Output pin of reference frequency. The frequency from pin 19 can be taken out as 3 V <sub>P-P</sub> swing.   |                             |     |      |    |  |
| 18      | REF <sub>in</sub> 2          | –                    | 2.45            | Input pin of reference frequency. This pin should be grounded through capacitor.   |                             |     |      |    |  |
| 19      | REF <sub>in</sub> 1          | –                    | 2.45            | Input pin of reference frequency. This pin can use as an input pin of reference frequency buffer. This pin should be equipped with external 16.368 MHz oscillator (example: TCXO). |                             |     |      |    |  |
| 20      | V <sub>CC</sub> (REF Block)  | 2.7 to 3.3           | –               | Supply voltage pin of reference block. This pin should be externally equipped with bypass capacitor to minimize ground impedance.  |                             |     |      |    |  |
| 21      | GND(REF Block)               | 0                    | –               | Ground pin of reference block.   |                             |     |      |    |  |
| 22      | 2ndIF <sub>out</sub>         | –                    | 1.80            | Output pin of 2nd IF amplifier. This pin output 4.092 MHz. This pin should be equipped with external buffer amplifier to adjust level to next stage on user's system.              |                             |     |      |    |  |
| 23      | V <sub>CC</sub> (2nd IF-AMP) | 2.7 to 3.3           | –               | Supply voltage pin of 2nd IF amplifier. This pin should be externally equipped with bypass capacitor to minimize ground impedance.   |                             |     |      |    |  |
| 24      | 2ndIF <sub>bypass</sub>      | –                    | 2.10            | Bypass pin of 2nd IF amplifier. This pin should be grounded through capacitor.   |                             |     |      |    |  |
| 25      | 2ndIF <sub>in</sub> 2        | –                    | 2.10            | Pin of 2nd IF amplifier input 2. This pin should be grounded through capacitor.  |                             |     |      |    |  |
| 26      | 2ndIF <sub>in</sub> 1        | –                    | 2.10            | Pin of 2nd IF amplifier input 1. 2nd IF filter can be inserted between 26 and 28.  |                             |     |      |    |  |
| 27      | GND(2nd IF-AMP)              | 0                    | –               | Ground pin of 2nd IF amplifier.  |                             |     |      |    |  |

| Pin No. | Pin Name                 | Applied Voltage (V) | Pin Voltage (V) | Function and Application  | Internal Equivalent Circuit |
|---------|--------------------------|---------------------|-----------------|---|-----------------------------|
| 28      | IF-MIX <sub>out</sub>    | –                   | 1.0             | Output pin of IF mixer.<br>IF mixer output signal goes through gain control amplifier before this emitter follower output port. |                             |
| 29      | V <sub>cc</sub> (IF-MIX) | 2.7 to 3.3          | –               | Supply voltage pin of IF mixer.<br>This pin should be externally equipped with bypass capacitor to minimize ground impedance.   |                             |
| 30      | V <sub>gc</sub> (IF-MIX) | 0 to 3.3            | –               | Gain control voltage pin of IF mixer output amplifier. This voltage performs forward control (V <sub>gc</sub> up → Gain down).  |                             |
| 31      | IF-MIX <sub>in</sub>     | –                   | 1.97            | Input pin of IF mixer.  |                             |
| 32      | GND(IF-MIX)              | 0                   | –               | Ground pin of IF mixer.   |                             |

**Caution** Ground pattern on the board must be formed as wide as possible to minimize ground impedance.

**ABSOLUTE MAXIMUM RATINGS**

| Parameter                     | Symbol               | Test Conditions                    | Ratings     | Unit |
|-------------------------------|----------------------|------------------------------------|-------------|------|
| Supply Voltage                | V <sub>CC</sub>      | T <sub>A</sub> = +25°C             | 3.6         | V    |
| Total Circuit Current         | I <sub>CCTotal</sub> | T <sub>A</sub> = +25°C             | 100         | mA   |
| Power Dissipation             | P <sub>D</sub>       | T <sub>A</sub> = +85°C <b>Note</b> | 360         | mW   |
| Operating Ambient Temperature | T <sub>A</sub>       |                                    | –40 to +85  | °C   |
| Storage Temperature           | T <sub>stg</sub>     |                                    | –55 to +150 | °C   |

**Note** Mounted on double-sided copper-clad 50 × 50 × 1.6 mm epoxy glass PWB

**RECOMMENDED OPERATING RANGE**

| Parameter                        | Symbol               | MIN. | TYP.     | MAX. | Unit |
|----------------------------------|----------------------|------|----------|------|------|
| Supply Voltage                   | V <sub>CC</sub>      | 2.7  | 3.0      | 3.3  | V    |
| Operating Ambient Temperature    | T <sub>A</sub>       | –40  | +25      | +85  | °C   |
| RF Input Frequency               | f <sub>RFin</sub>    | –    | 1 575.42 | –    | MHz  |
| 1st LO Oscillating Frequency     | f <sub>1stLOin</sub> | –    | 1 636.80 | –    | MHz  |
| 1st IF Input Frequency           | f <sub>1stIFin</sub> | –    | 61.380   | –    | MHz  |
| 2nd LO Input Frequency           | f <sub>2ndLOin</sub> | –    | 65.472   | –    | MHz  |
| 2nd IF Input Frequency           | f <sub>2ndIFin</sub> | –    | 4.092    | –    | MHz  |
| Reference Input/Output Frequency | f <sub>REFin</sub>   | –    | 16.368   | –    | MHz  |
|                                  | f <sub>REFout</sub>  |      |          |      |      |
| LO Output Frequency              | f <sub>LOout</sub>   | –    | 8.184    | –    | MHz  |



**ELECTRICAL CHARACTERISTICS (T<sub>A</sub> = +25°C, V<sub>CC</sub> = 3.0 V)**

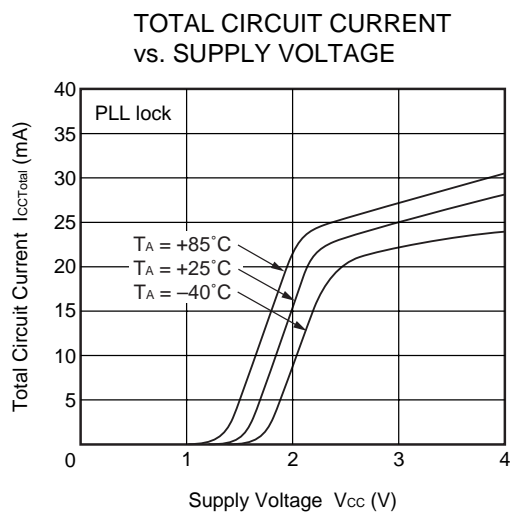
| Parameter  | Symbol                   | Test Conditions   | MIN.  | TYP.  | MAX. | Unit              |
|--|--------------------------|---|-------|-------|------|-------------------|
| Total Circuit Current  | I <sub>CCTotal</sub>     | All block operating @ PLL lock  | 19.0  | 25.0  | 35.0 | mA                |
| Power-save Dark Current  | I <sub>CC(PD)</sub>      | Pin 15 = Pin 16 = 0 V   | –     | –     | 5    | $\mu$ A           |
| Reference Block Circuit Current  | I <sub>CCREF</sub>       | Pin 15 = 0 V, Pin 16 = 3 V  | –     | 3     | 4    | mA                |
| Pre-amplifier Block (f <sub>RFin</sub> = 1 575.42 MHz, Z <sub>S</sub> = Z <sub>L</sub> = 50 $\Omega$ )   |                          |   |       |       |      |                   |
| Circuit Current 1  | I <sub>CC1</sub>         | No Signals  | 1.65  | 2.50  | 3.50 | mA                |
| Power Gain   | G <sub>P</sub>           | Input/Output matching, P <sub>RFin</sub> = –40 dBm                            | 12.5  | 15.5  | 18.5 | dB                |
| Noise Figure   | NF                       | Input/Output matching   | –     | 3.2   | 4.0  | dB                |
| RF Down-converter Block (f <sub>RFin</sub> = 1 575.42 MHz, f <sub>1stLOin</sub> = 1 636.80 MHz, P <sub>LOin</sub> = –10 dBm, Z <sub>S</sub> = Z <sub>L</sub> = 50 $\Omega$ ) |                          |   |       |       |      |                   |
| Circuit Current 2  | I <sub>CC2</sub>         | No Signals  | 5.2   | 7.0   | 9.9  | mA                |
| RF Conversion Gain   | CG <sub>RF</sub>         | P <sub>RFin</sub> = –40 dBm   | 15.5  | 18.5  | 21.5 | dB                |
| RF-SSB Noise Figure  | NF <sub>RF</sub>         |   | –     | 10.5  | 13.5 | dB                |
| RF Saturated Output Power  | P <sub>O(sat)RF</sub>    | P <sub>RFin</sub> = –10 dBm   | –4    | –1    | –    | dBm               |
| IF Down-converter Block (f <sub>1stIFin</sub> = 61.38 MHz, f <sub>2ndLOin</sub> = 65.472 MHz, Z <sub>S</sub> = 50 $\Omega$ , Z <sub>L</sub> = 2 k $\Omega$ )                 |                          |   |       |       |      |                   |
| Circuit Current 3  | I <sub>CC3</sub>         | No Signals  | 2.7   | 3.5   | 5.0  | mA                |
| IF Conversion Voltage Gain   | CG <sub>(GV)IF</sub>     | at Maximum Gain, P <sub>1stIFin</sub> = –50 dBm                               | 40    | 43    | 46   | dB                |
| IF-SSB Noise Figure  | NF <sub>IF</sub>         | at Maximum Gain   | –     | 11.5  | 14.5 | dB                |
| 2nd IF Saturated Output Power  | P <sub>O(sat)2ndIF</sub> | at Maximum Gain, P <sub>1stIFin</sub> = –20 dBm                               | –9.0  | –6.0  | –    | dBm               |
| Gain Control Voltage   | V <sub>GC</sub>          | Voltage at Maximum Gain CG <sub>IF</sub>                                      | –     | –     | 1.0  | V                 |
| Gain Control Range   | D <sub>GC</sub>          | P <sub>1stIFin</sub> = –50 dBm  | 20    | –     | –    | dB                |
| 2nd IF Amplifier (f <sub>2ndIFin</sub> = 4.092 MHz, Z <sub>S</sub> = 50 $\Omega$ , Z <sub>L</sub> = 2 k $\Omega$ )   |                          |   |       |       |      |                   |
| Circuit Current 4  | I <sub>CC4</sub>         | No Signals  | 0.8   | 1.0   | 1.6  | mA                |
| Voltage Gain   | G <sub>V</sub>           | P <sub>2ndIFin</sub> = –60 dBm  | 40    | 43    | 46   | dB                |
| 2nd IF Saturated Output Power  | P <sub>O(sat)2ndIF</sub> | P <sub>2ndIFin</sub> = –30 dBm  | –14.0 | –11.0 | –    | dBm               |
| PLL Synthesizer Block  |                          |   |       |       |      |                   |
| Circuit Current 5  | I <sub>CC5</sub>         | PLL All Block Operating   | 8.7   | 11.0  | 14.4 | mA                |
| Loop Filter Output (High)  | V <sub>oH</sub>          |   | 2.8   | –     | –    | V                 |
| Loop Filter Output (Low)   | V <sub>oL</sub>          |   | –     | –     | 0.4  | V                 |
| Reference Minimum Input Level  | V <sub>REFin</sub>       | Z <sub>L</sub> = 100 k $\Omega$ /0.6 pF<br>Impedance of measurement equipment | 200   | –     | –    | mV <sub>P-P</sub> |
| Reference Output Swing   | V <sub>REFout</sub>      | Z <sub>L</sub> = 100 k $\Omega$ /0.6 pF<br>Impedance of measurement equipment | 2.9   | 3.0   | –    | V <sub>P-P</sub>  |

**STANDARD CHARACTERISTICS ( $T_A = +25^\circ\text{C}$ ,  $V_{CC} = 3.0\text{ V}$ )**

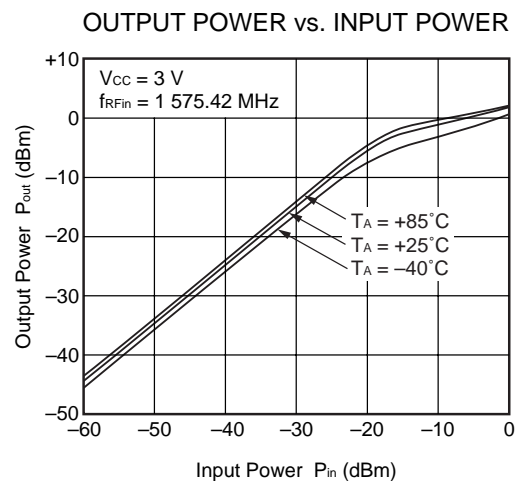
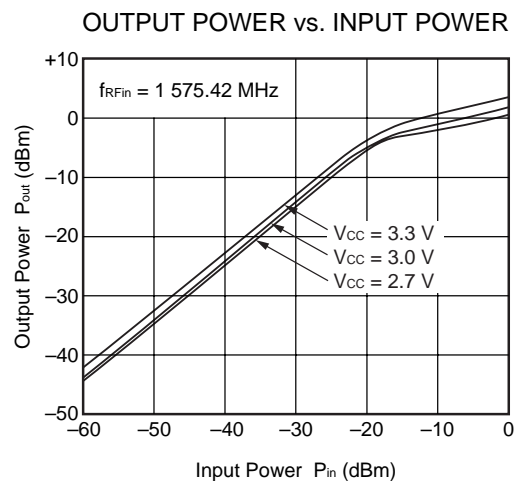
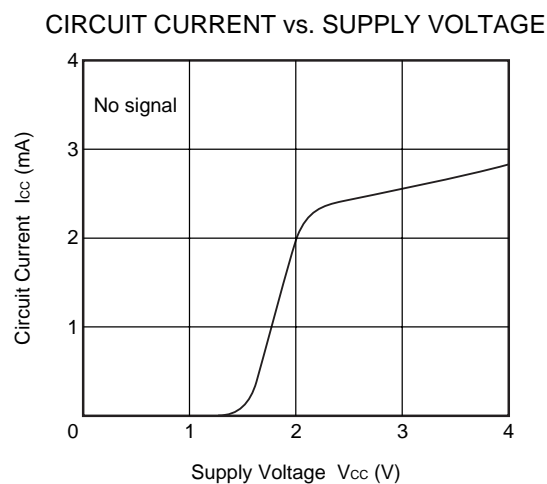
| Parameter  | Symbol        | Test Conditions  | Reference | Unit   |
|--|---------------|--|-----------|--------|
| Pre-amplifier Block ( $f_{RFin} = 1\,575.42\text{ MHz}$ , $Z_S = Z_L = 50\,\Omega$ )         |               |  |           |        |
| Input 1dB Compression Level  | $P_{in(1dB)}$ | Input/Output matching  | -20       | dBm    |
| RF Down-converter Block ( $P_{1stLOin} = -10\text{ dBm}$ , $Z_S = Z_L = 50\,\Omega$ )        |               |  |           |        |
| LO Leakage to IF Pin   | $LO_{if}$     | $f_{1stLOin} = 1\,636.80\text{ MHz}$   | -37       | dBm    |
| LO Leakage to RF Pin   | $LO_{rf}$     | $f_{1stLOin} = 1\,636.80\text{ MHz}$   | -36       | dBm    |
| Input 3rd Order Intercept Point  | $IIP_{3(RF)}$ | $f_{RFin1} = 1\,600\text{ MHz}$ , $f_{RFin2} = 1\,605\text{ MHz}$ ,<br>$f_{1stLOin} = 1\,660\text{ MHz}$     | -15       | dBm    |
| IF Down-converter Block (1st LO oscillating, $Z_S = 50\,\Omega$ , $Z_L = 2\text{ k}\Omega$ ) |               |  |           |        |
| LO Leakage to 1st IF Pin   | $LO_{1stif}$  | $f_{2ndLOin} = 65.472\text{ MHz}$  | -90       | dBm    |
| LO Leakage to 2nd IF Pin   | $LO_{2ndif}$  | $f_{2ndLOin} = 65.472\text{ MHz}$  | -63       | dBm    |
| Input 3rd Order Intercept Point  | $IIP_{3(IF)}$ | $f_{1stIFin1} = 61.38\text{ MHz}$ , $f_{1stIFin2} = 61.48\text{ MHz}$ ,<br>$f_{2ndLOin} = 65.472\text{ MHz}$ | -27.5     | dBm    |
| PLL Synthesizer Block  |               |  |           |        |
| Phase Comparing Frequency  | $f_{PD}$      | PLL loop   | 8.184     | MHz    |
| VCO Block  |               |  |           |        |
| Phase Noise  | C/N           | PLL Loop, $\Delta 1\text{ kHz}$ of VCO wave  | 83        | dBc/Hz |

★ TYPICAL CHARACTERISTICS (Unless otherwise specified,  $T_A = +25^\circ\text{C}$ ,  $V_{CC} = 3.0\text{ V}$ )

## — IC TOTAL —

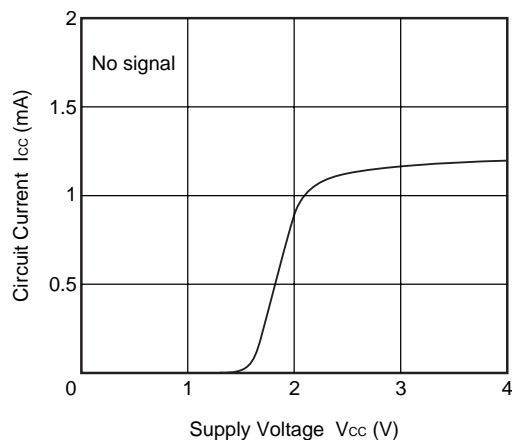


## — PRE-AMPLIFIER BLOCK —

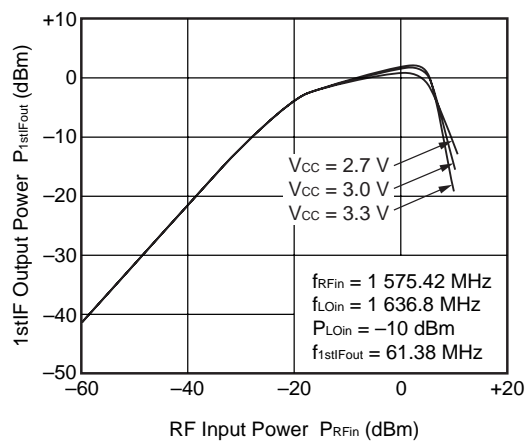


## — RF DOWN-CONVERTER BLOCK —

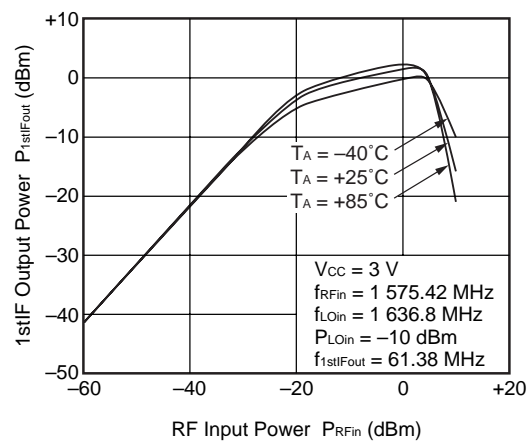
CIRCUIT CURRENT vs. SUPPLY VOLTAGE



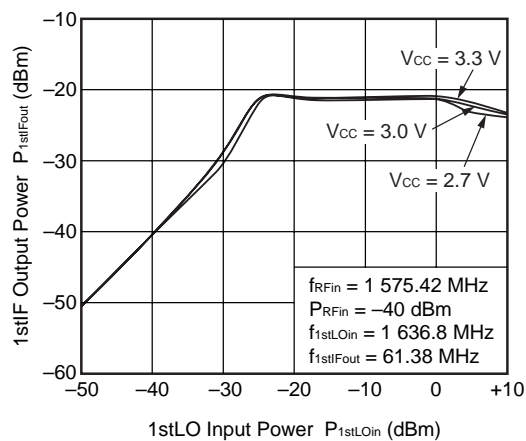
1stIF OUTPUT POWER vs. RF INPUT POWER



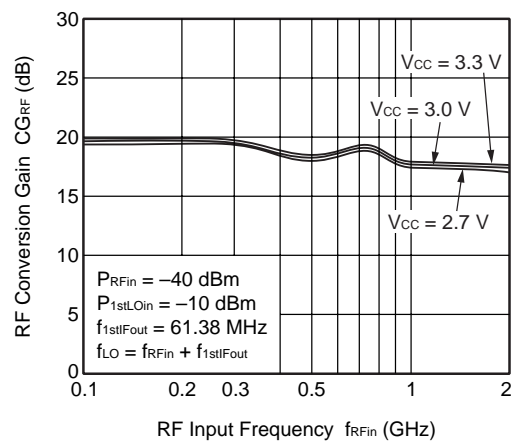
1stIF OUTPUT POWER vs. RF INPUT POWER

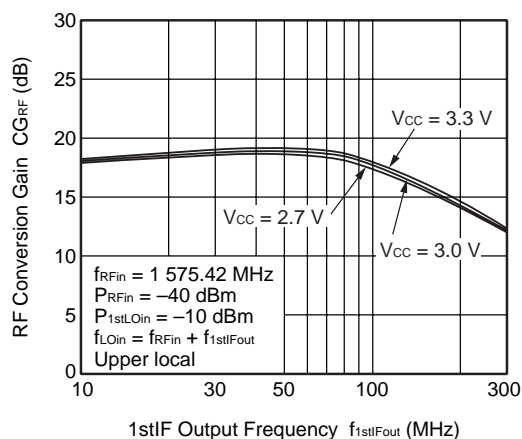
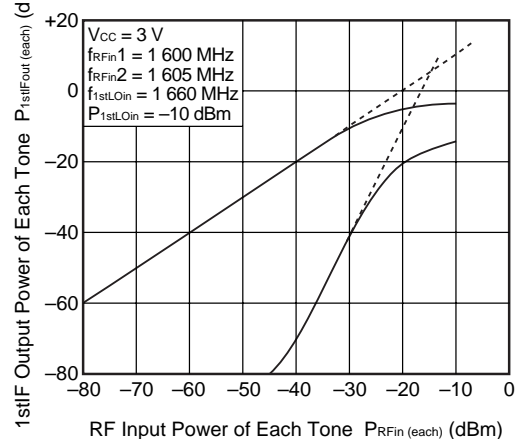


1stIF OUTPUT POWER vs. 1stLO INPUT POWER



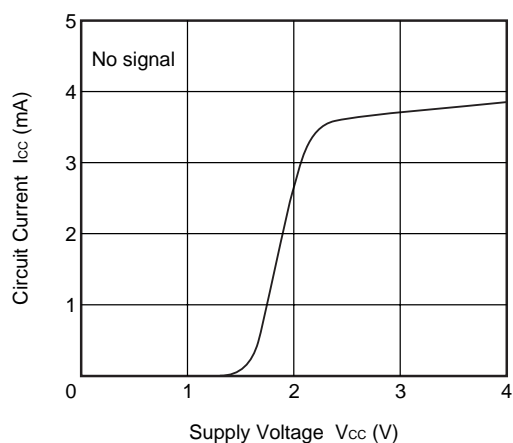
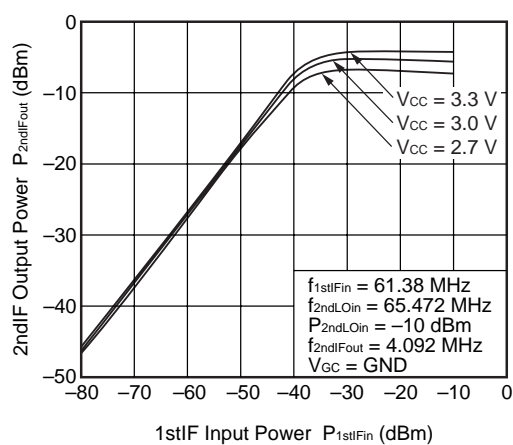
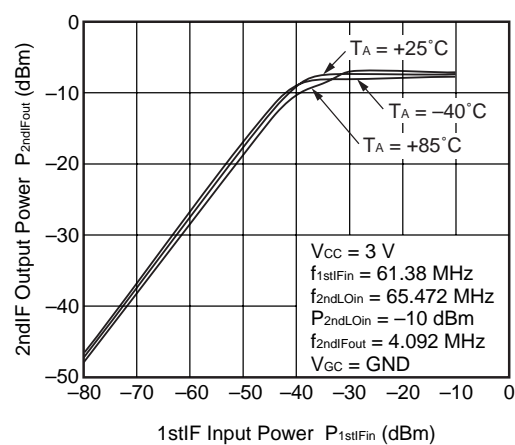
RF CONVERSION GAIN vs. RF INPUT FREQUENCY

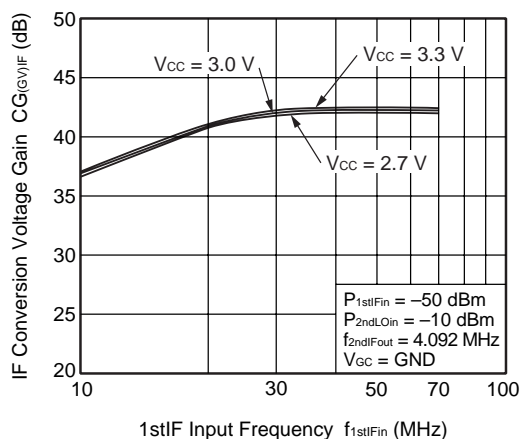
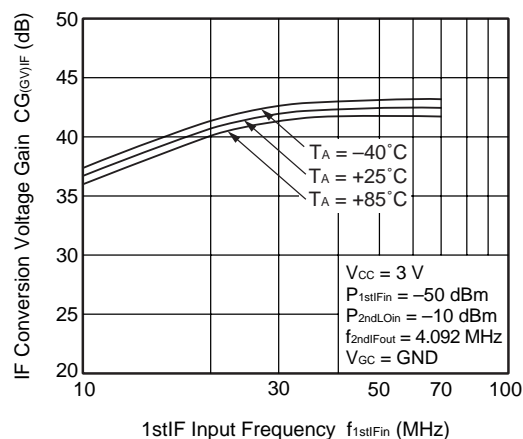
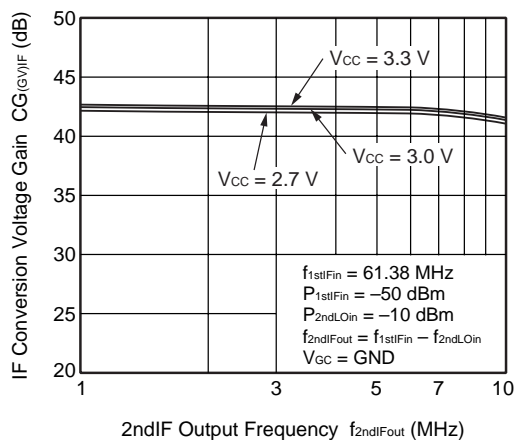
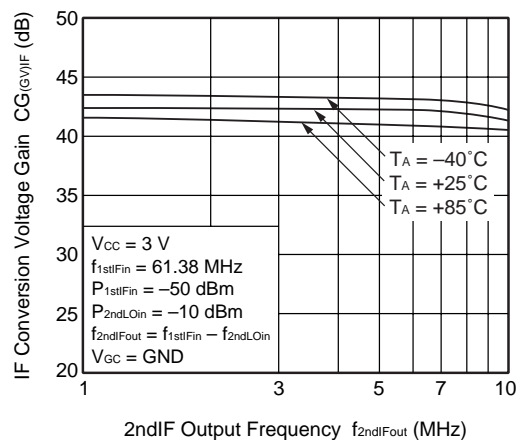
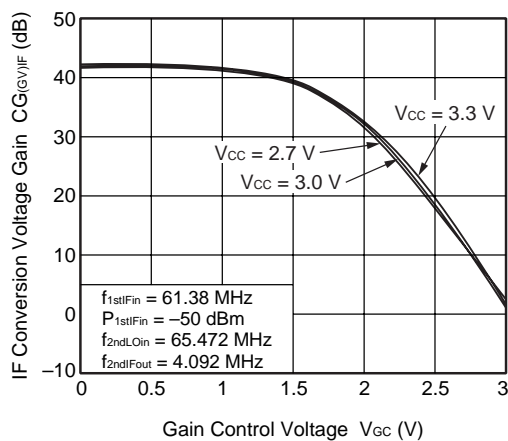
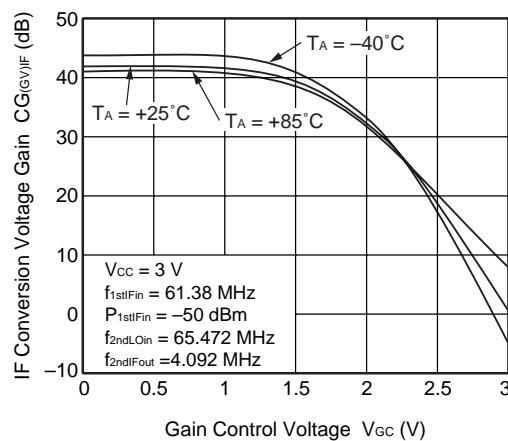


RF CONVERSION GAIN vs.  
1stIF OUTPUT FREQUENCY1stIF OUTPUT POWER OF EACH TONE  
vs. RF INPUT POWER OF EACH TONE

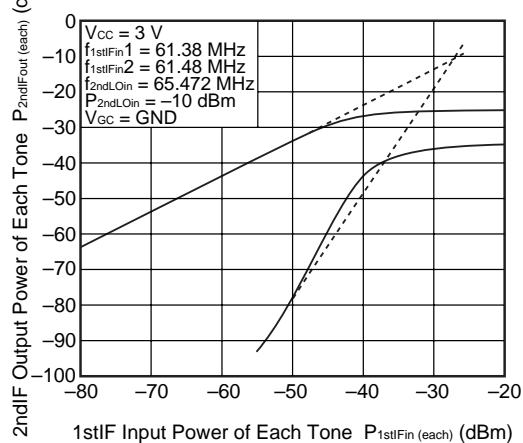
## — IF DOWN-CONVERTER BLOCK —

CIRCUIT CURRENT vs. SUPPLY VOLTAGE

2ndIF OUTPUT POWER  
vs. 1stIF INPUT POWER2ndIF OUTPUT POWER  
vs. 1stIF INPUT POWER

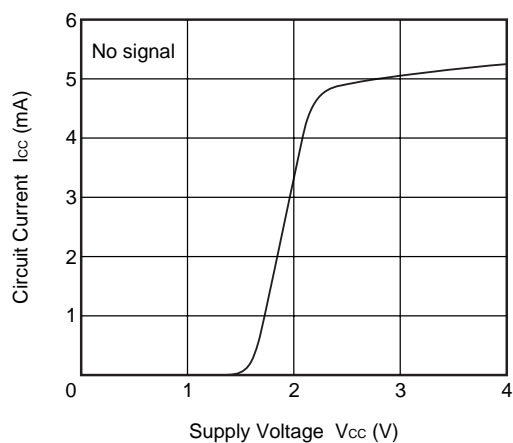
IF CONVERSION VOLTAGE GAIN  
vs. 1stIF INPUT FREQUENCYIF CONVERSION VOLTAGE GAIN  
vs. 1stIF INPUT FREQUENCYIF CONVERSION VOLTAGE GAIN  
vs. 2ndIF OUTPUT FREQUENCYIF CONVERSION VOLTAGE GAIN  
vs. 2ndIF OUTPUT FREQUENCYIF CONVERSION VOLTAGE GAIN  
vs. GAIN CONTROL VOLTAGEIF CONVERSION VOLTAGE GAIN  
vs. GAIN CONTROL VOLTAGE

2ndIF OUTPUT POWER OF EACH TONE  
vs. 1stIF INPUT POWER OF EACH TONE

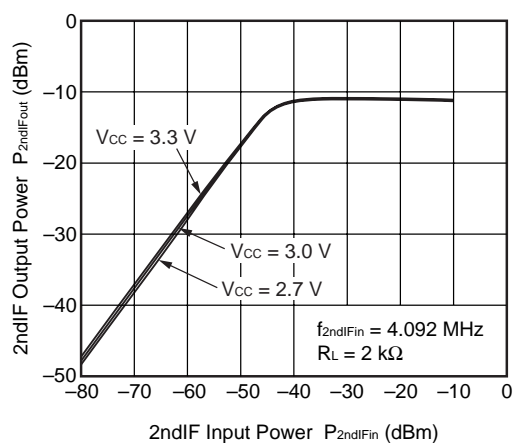


### — IF AMPLIFIER BLOCK —

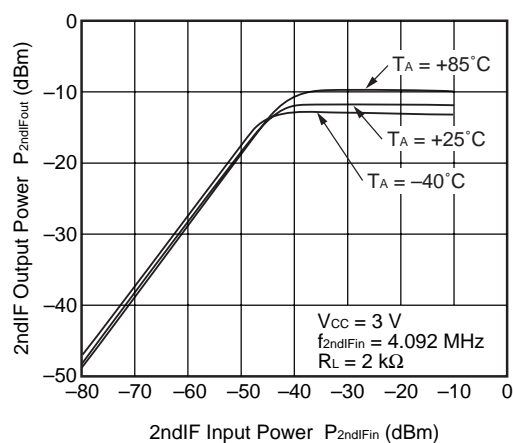
CIRCUIT CURRENT vs. SUPPLY VOLTAGE

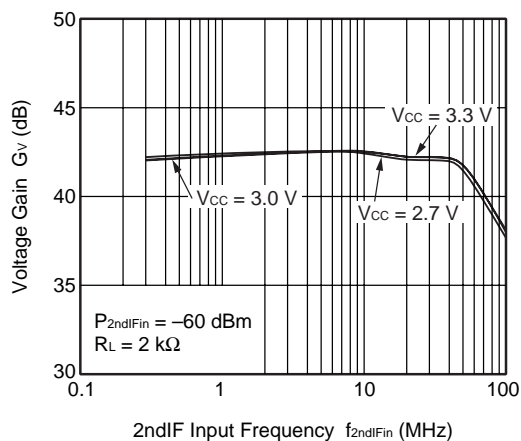
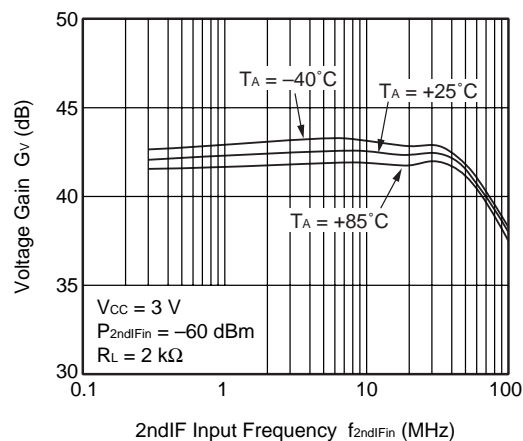


2ndIF OUTPUT POWER  
vs. 2ndIF INPUT POWER



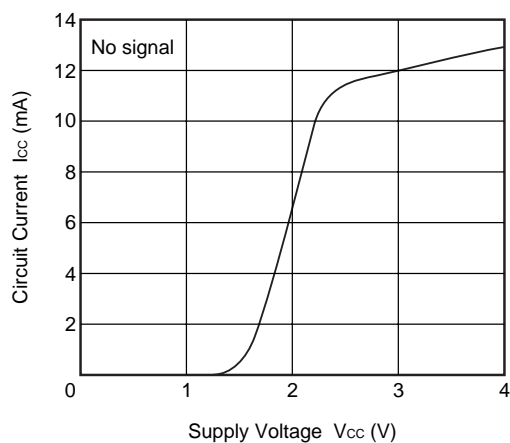
2ndIF OUTPUT POWER  
vs. 2ndIF INPUT POWER



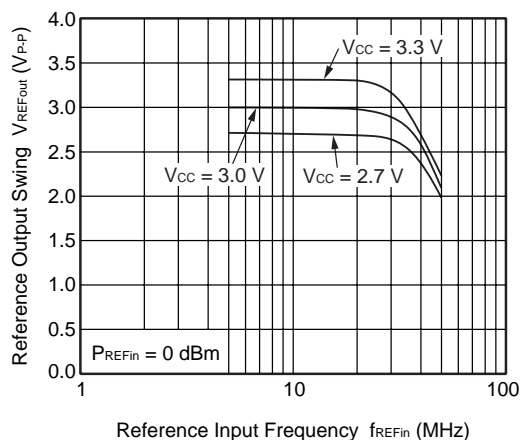
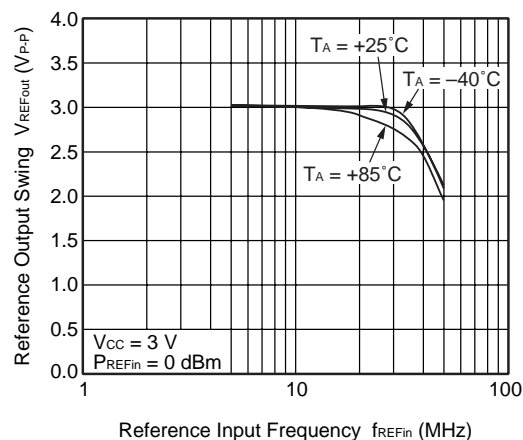
VOLTAGE GAIN vs.  
2ndIF INPUT FREQUENCYVOLTAGE GAIN vs.  
2ndIF INPUT FREQUENCY

## — PLL SYNTHESIZER BLOCK —

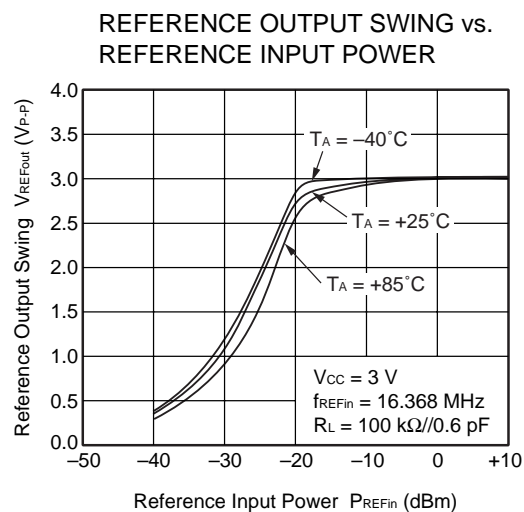
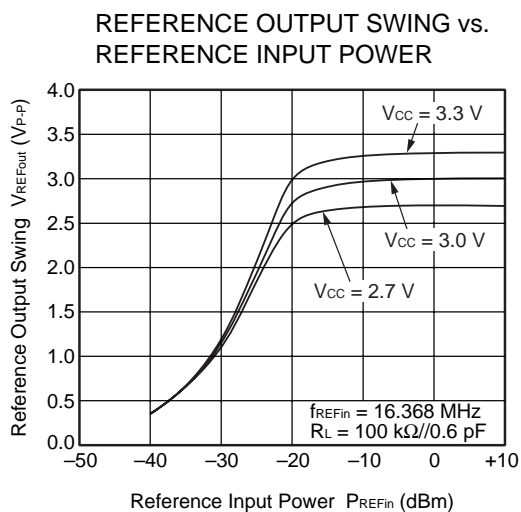
CIRCUIT CURRENT vs. SUPPLY VOLTAGE



## — REFERENCE BLOCK —

REFERENCE OUTPUT SWING vs.  
REFERENCE INPUT FREQUENCYREFERENCE OUTPUT SWING vs.  
REFERENCE INPUT FREQUENCY

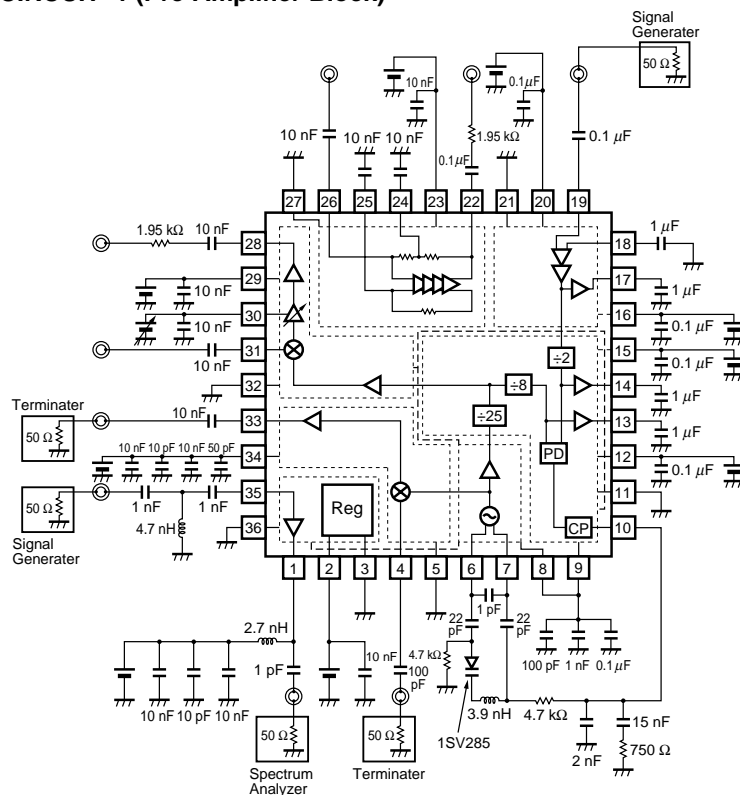




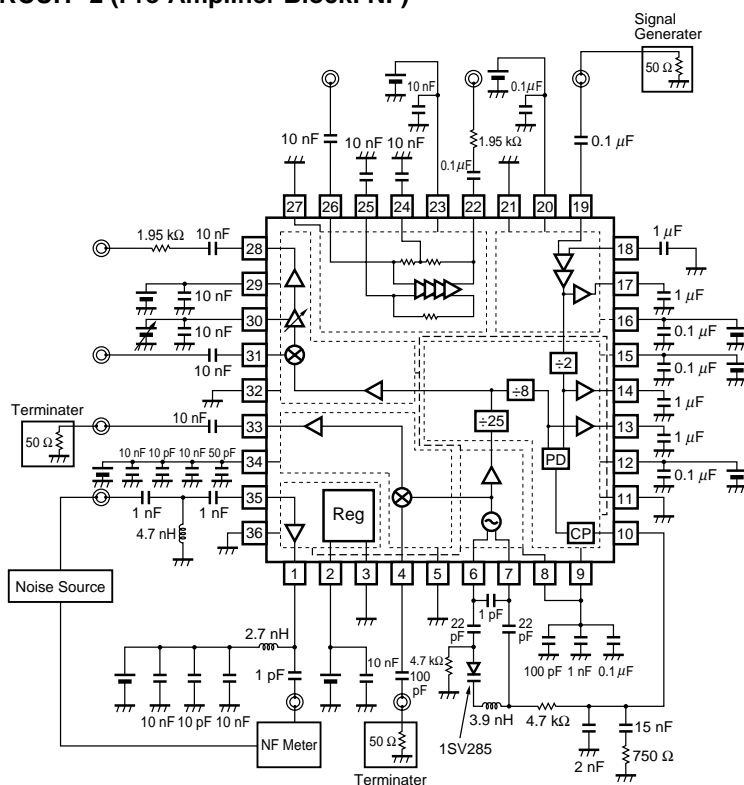
**Remark** The graphs indicate nominal characteristics.

## ★ MEASUREMENT CIRCUIT

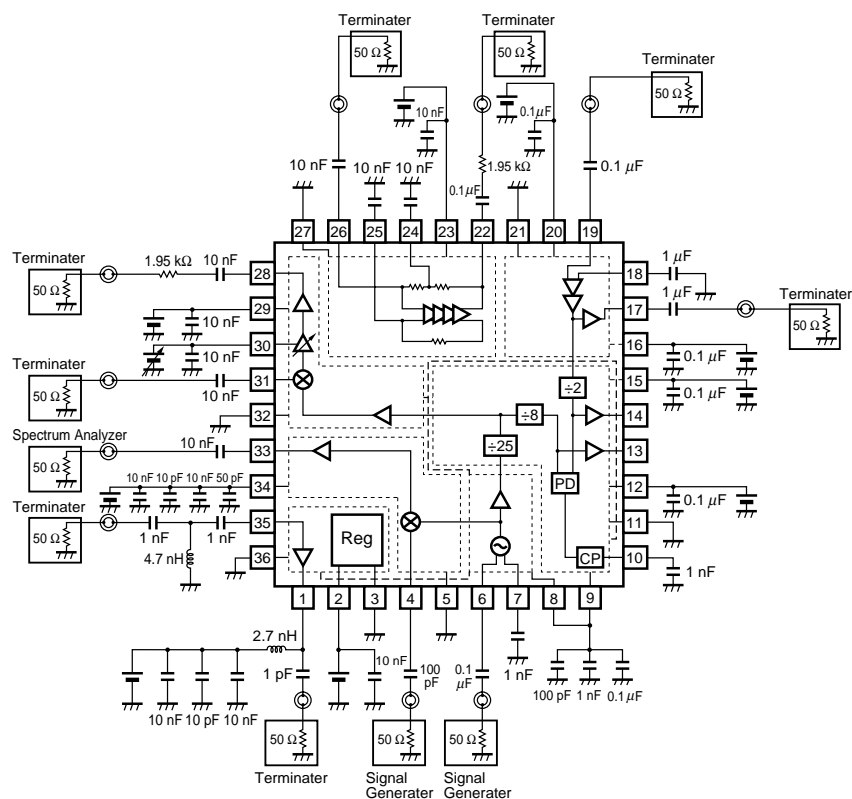
## MEASUREMENT CIRCUIT 1 (Pre-Amplifier Block)



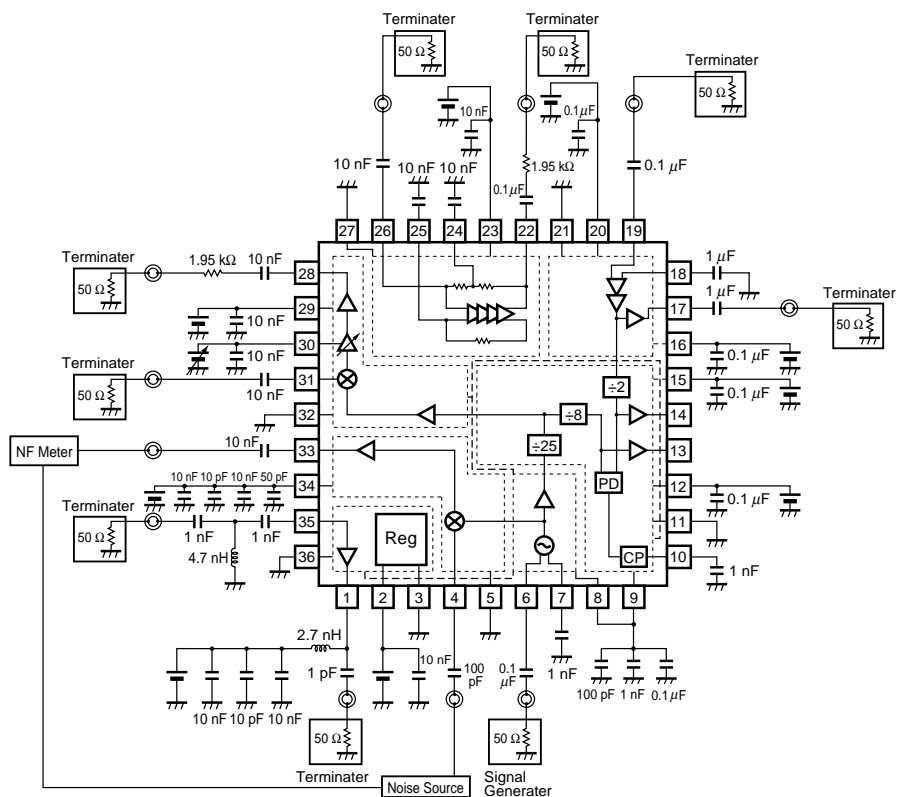
## MEASUREMENT CIRCUIT 2 (Pre-Amplifier Block: NF)

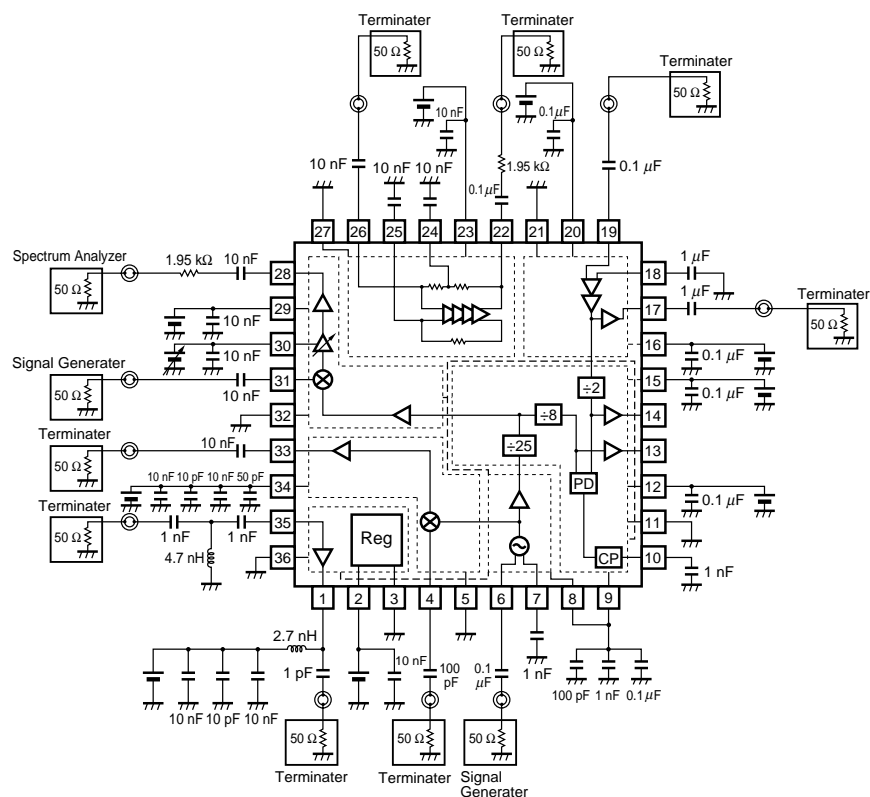
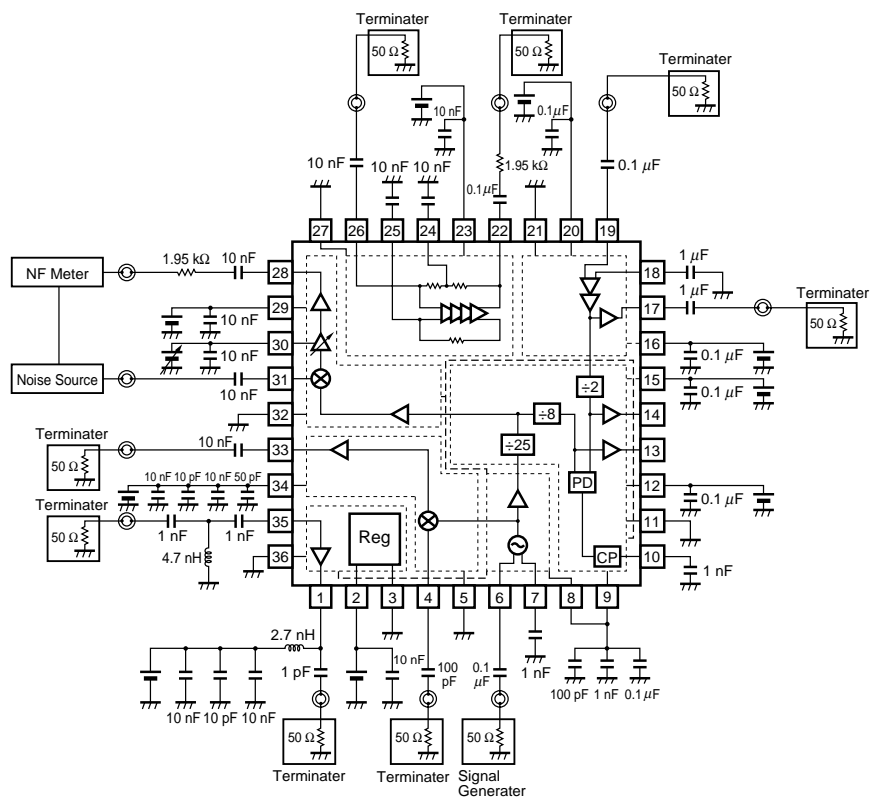


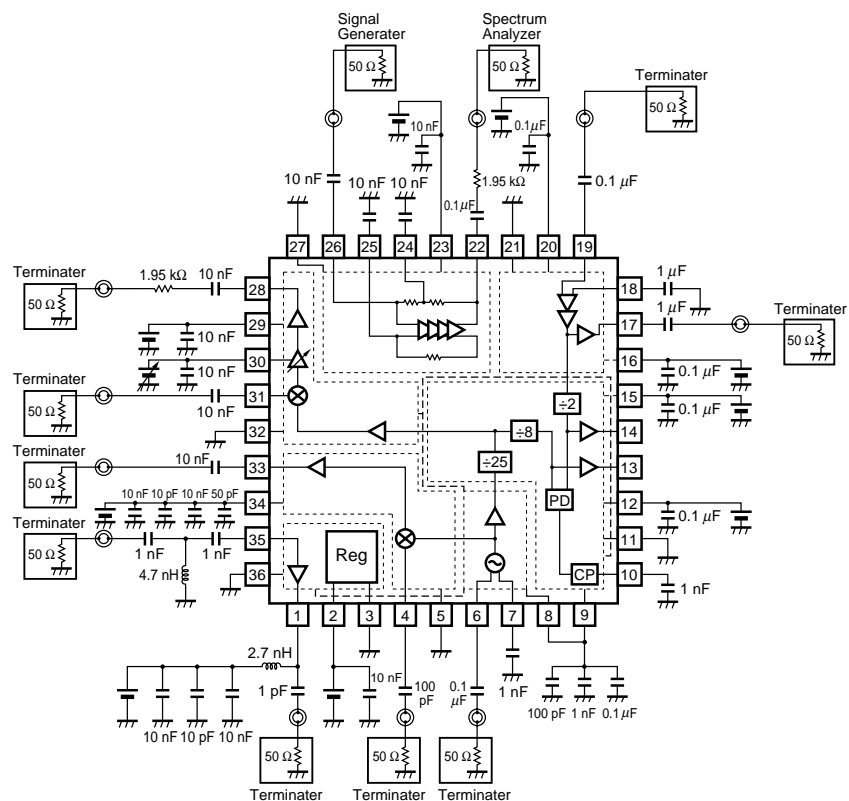
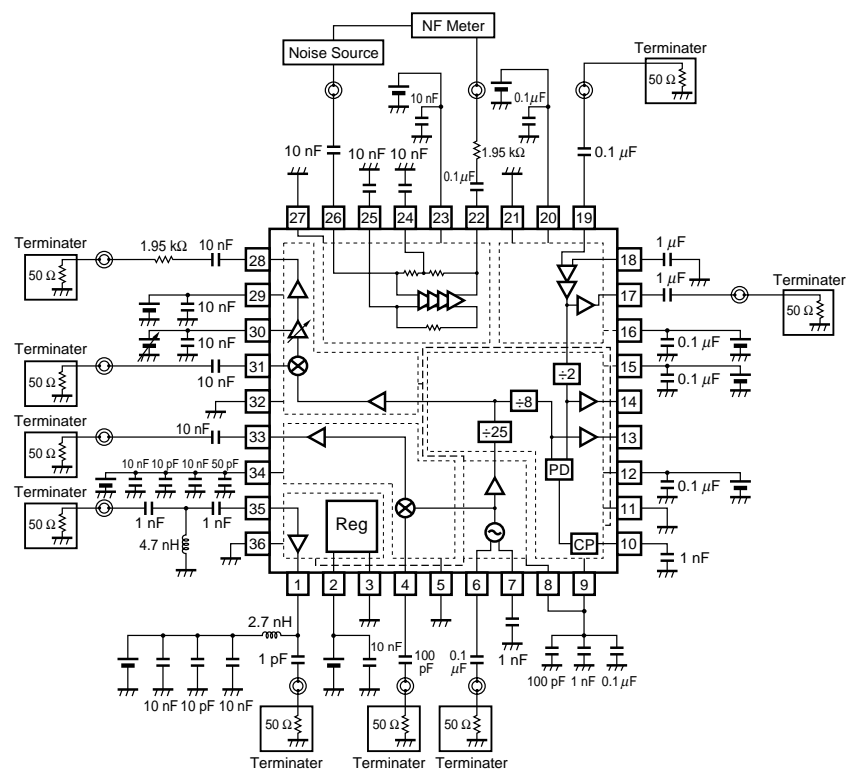
## MEASUREMENT CIRCUIT 3 (RF-MIX Block)



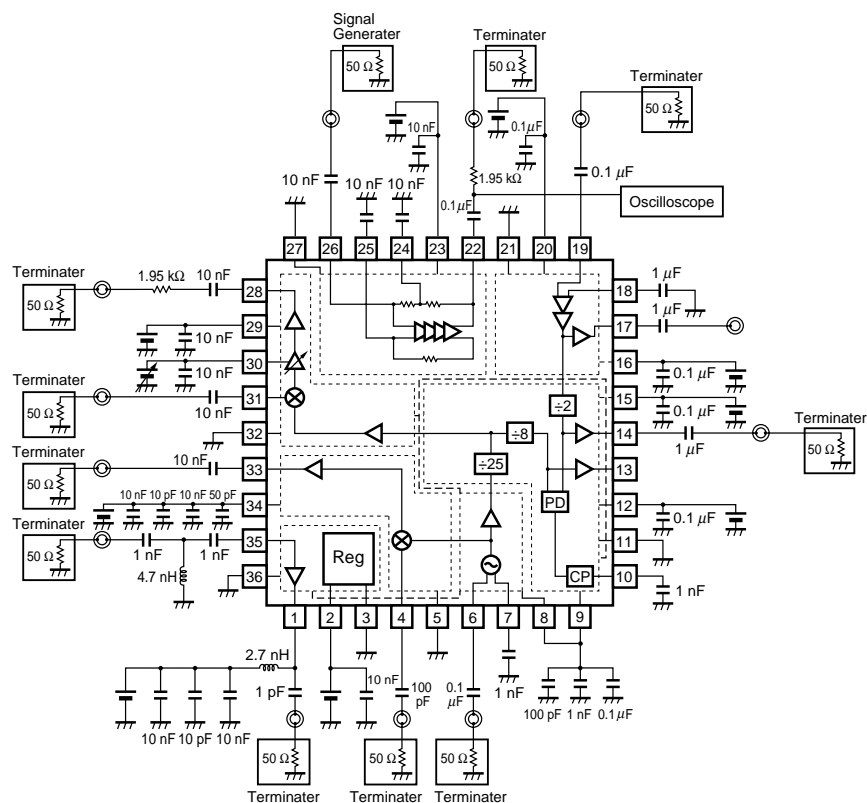
## MEASUREMENT CIRCUIT 4 (RF-MIX Block: NF)



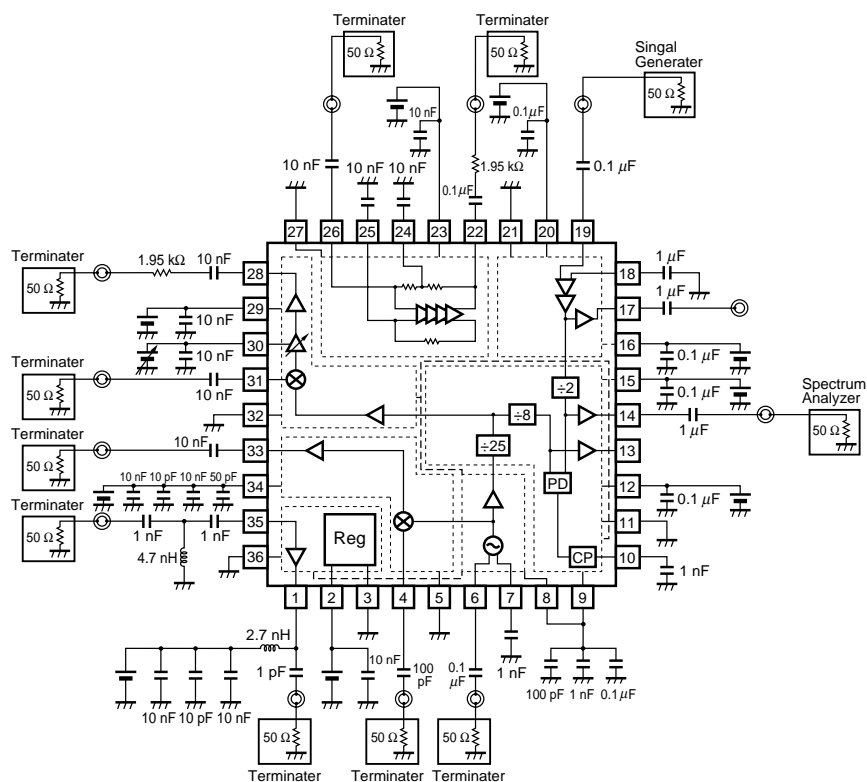
**MEASUREMENT CIRCUIT 5 (IF Down-Converter Block)****MEASUREMENT CIRCUIT 6 (IF Down-Converter Block: NF)**

**MEASUREMENT CIRCUIT 7 (IF Amplifier Block)****MEASUREMENT CIRCUIT 8 (IF Amplifier Block: NF)**

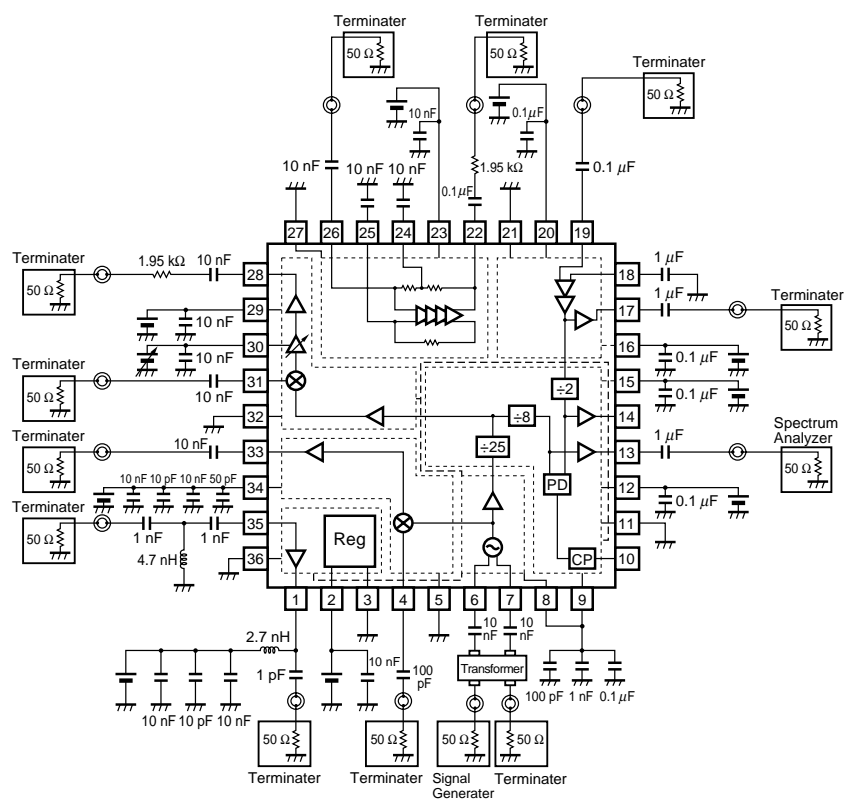
### MEASUREMENT CIRCUIT 9 (IF Amplifier Block: Output Swing)



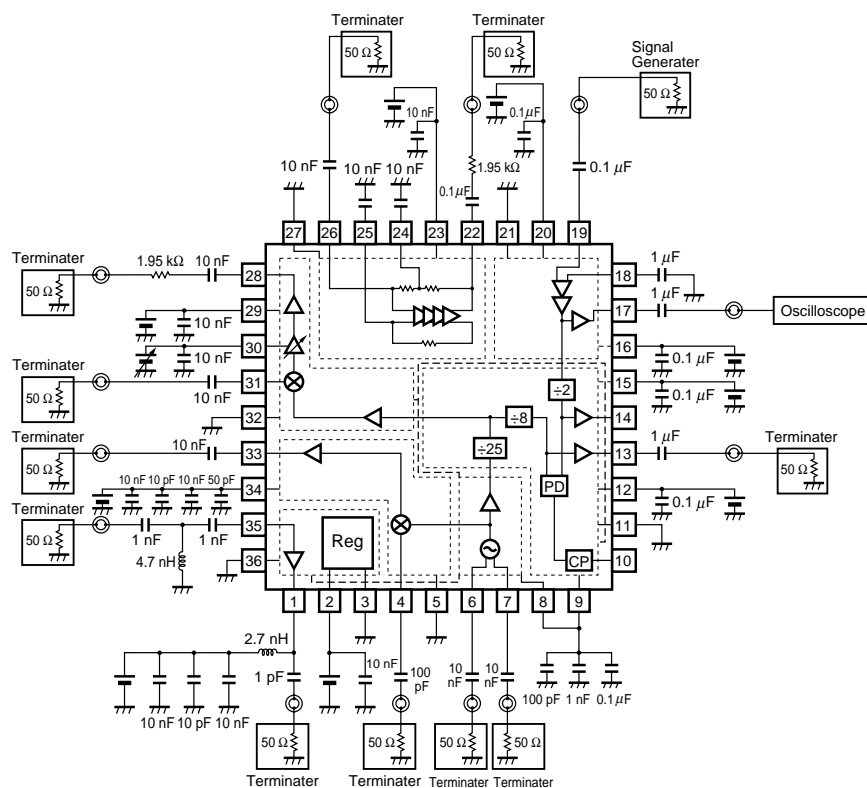
### MEASUREMENT CIRCUIT 10 (1/2 Prescaler)



## MEASUREMENT CIRCUIT 11 (1/200 Prescaler)

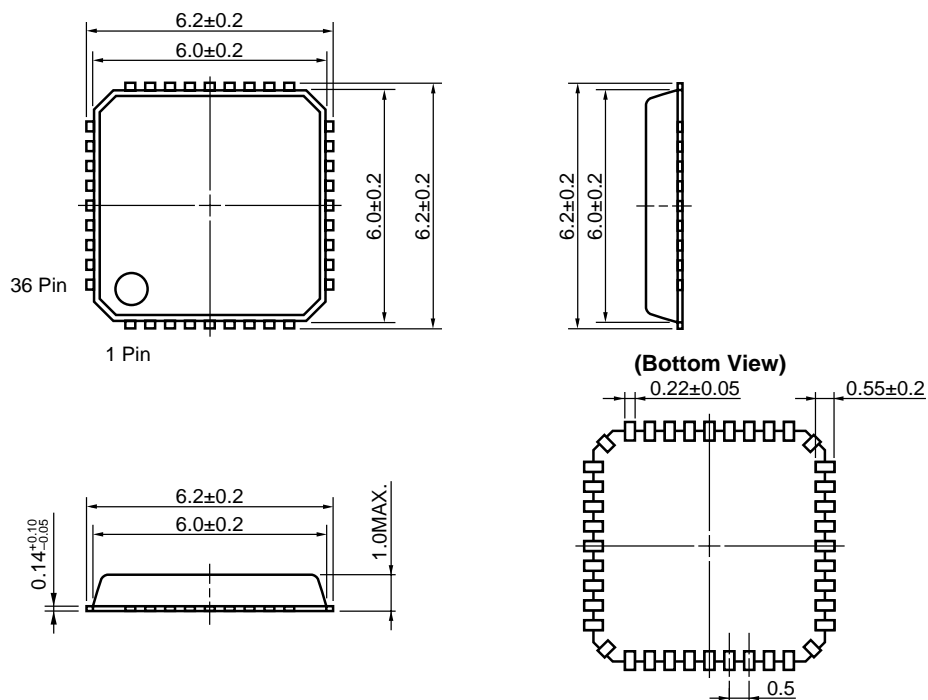


## MEASUREMENT CIRCUIT 12 (REF Output)



## ★ PACKAGE DIMENSIONS

36-PIN PLASTIC QFN (UNIT: mm)





**NOTES ON CORRECT USE**

- (1) Observe precautions for handling because of electro-static sensitive devices.
- (2) Form a ground pattern as widely as possible to minimize ground impedance (to prevent abnormal oscillation).
- (3) Keep the wiring length of the ground pins as short as possible.
- (4) Connect a bypass capacitor (example: 1 000 pF) to the V<sub>cc</sub> pin.
- (5) High-frequency signal I/O pins must be coupled with the external circuit using a coupling capacitor.

**★ RECOMMENDED SOLDERING CONDITIONS**

This product should be soldered and mounted under the following recommended conditions. For soldering methods and conditions other than those recommended below, contact your nearby sales office.

| Soldering Method | Soldering Conditions  | Condition Symbol |
|------------------|---|------------------|
| Infrared Reflow  | Peak temperature (package surface temperature) : 260°C or below<br>Time at peak temperature : 10 seconds or less<br>Time at temperature of 220°C or higher : 60 seconds or less<br>Preheating time at 120 to 180°C : 120±30 seconds<br>Maximum number of reflow processes : 3 times<br>Maximum chlorine content of rosin flux (% mass) : 0.2%(Wt.) or below | IR260            |
| VPS              | Peak temperature (package surface temperature) : 215°C or below<br>Time at temperature of 200°C or higher : 25 to 40 seconds<br>Preheating time at 120 to 150°C : 30 to 60 seconds<br>Maximum number of reflow processes : 3 times<br>Maximum chlorine content of rosin flux (% mass) : 0.2%(Wt.) or below  | VP215            |
| Wave Soldering   | Peak temperature (molten solder temperature) : 260°C or below<br>Time at peak temperature : 10 seconds or less<br>Preheating temperature (package surface temperature) : 120°C or below<br>Maximum number of flow processes : 1 time<br>Maximum chlorine content of rosin flux (% mass) : 0.2%(Wt.) or below  | WS260            |
| Partial Heating  | Peak temperature (pin temperature) : 350°C or below<br>Soldering time (per side of device) : 3 seconds or less<br>Maximum chlorine content of rosin flux (% mass) : 0.2%(Wt.) or below  | HS350            |

**Caution** Do not use different soldering methods together (except for partial heating).

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M8E 00.4-0110

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Sales Engineering Group, Sales Division

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Subject: Compliance with EU Directives

CEL certifies, to its knowledge, that semiconductor and laser products detailed below are compliant with the requirements of European Union (EU) Directive 2002/95/EC Restriction on Use of Hazardous Substances in electrical and electronic equipment (RoHS) and the requirements of EU Directive 2003/11/EC Restriction on Penta and Octa BDE.

CEL Pb-free products have the same base part number with a suffix added. The suffix –A indicates that the device is Pb-free. The –AZ suffix is used to designate devices containing Pb which are exempted from the requirement of RoHS directive (\*). In all cases the devices have Pb-free terminals. All devices with these suffixes meet the requirements of the RoHS directive.

This status is based on CEL's understanding of the EU Directives and knowledge of the materials that go into its products as of the date of disclosure of this information.

| Restricted Substance per RoHS | Concentration Limit per RoHS (values are not yet fixed) | Concentration contained in CEL devices |     |
|-------------------------------|---|--|-----|
|                               |   | -A                                     | -AZ |
| Lead (Pb)                     | < 1000 PPM  | Not Detected                           | (*) |
| Mercury                       | < 1000 PPM  | Not Detected                           |     |
| Cadmium                       | < 100 PPM   | Not Detected                           |     |
| Hexavalent Chromium           | < 1000 PPM  | Not Detected                           |     |
| PBB                           | < 1000 PPM  | Not Detected                           |     |
| PBDE                          | < 1000 PPM  | Not Detected                           |     |

If you should have any additional questions regarding our devices and compliance to environmental standards, please do not hesitate to contact your local representative.

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